



SANYO Semiconductors

DATA SHEET

Monolithic Linear IC

L780S00 Series — 5 to 24V 1A 5-Pin Voltage Regulators with Strobe Pin

Features

- Output voltage

L780S05 : 5V	L780S08 : 8V	L780S09 : 9V
L780S10 : 10V	L780S12 : 12V	L780S15 : 15V
L780S18 : 18V		
- The strobe pin can be used to turn ON / OFF output voltage (active-low).
- 1A output current.
- On-chip thermal protector.
- On-chip overcurrent limiter.
- On-chip ASO protector.
- The use of package TO-220-5H (5 pins) facilitates mounting and thermal design.

Specifications

[Common to L780S00 series]

Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max	Pin 1	35	V
Strobe input voltage	V _{ST} max	Pin 4	18	V
Strobe input current	I _{ST} max	Pin 4	5	mA
Allowable power dissipation	P _d max		1.75	W
		T _c =25°C	20	W
Thermal resistance	θ _{j-c}		5	°C / W
Operating temperature	T _{opr}		-20 to +80	°C
Storage temperature	T _{stg}		-55 to +150	°C

Strobe Operating Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Strobe operation start voltage	V _{st(on)}		2.4	V
Strobe operation stop voltage	V _{st(off)}		0.5	V

- Any and all SANYO Semiconductor products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your SANYO Semiconductor representative nearest you before using any SANYO Semiconductor products described or contained herein in such applications.
- SANYO Semiconductor assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all SANYO Semiconductor products described or contained herein.

SANYO Semiconductor Co., Ltd.

TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

[L780S05]

Recommended Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings		Unit
Input voltage range	V _{IN}		7.5 to 20.0		V
Output current range	I _O		5 to 1000		mA

Operating Characteristics at T_j=25°C, V_{IN}=10V, I_O=500mA, V_{st}=0V, *Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output voltage	V _{O1}		4.8	5.0	5.2	V
	V _{O2}	7V≤V _{IN} ≤20V, 5mA≤V _{IN} ≤1A	4.75		5.25	V
Line regulation 1	ΔV _{OLN1}	7V≤V _{IN} ≤25V		3	100	mV
Line regulation 2	ΔV _{OLN2}	8V≤V _{IN} ≤12V		1	50	mV
Load regulation 1	ΔV _{OLD1}	5mA≤I _O ≤1.5A			100	mV
Load regulation 2	ΔV _{OLD2}	250mA≤I _O ≤750mA			50	mV
Current dissipation	I _{CC}				8.0	mA
Current dissipation variation (Line)	ΔI _{CCLN}	7V≤V _{IN} ≤25V			1.3	mA
Current dissipation variation (Load)	ΔI _{CCLD}	5mA≤I _O ≤1A			0.5	mA
Output noise voltage	V _{NO}	10Hz≤f≤100kHz*		40		µV
Ripple rejection	R _r	f=120Hz, 8V≤V _{IN} ≤18V	62	78		dB
Dropout voltage	V _{drop}	I _O =1A		2.0		V
Output short current	I _{OS}	V _{IN} =35V		0.75		A
Peak output current	I _{OP}			2.2		A
Output voltage at strobe mode	V _O (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			0.8	V
Current dissipation at strobe mode	I _{CC} (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			3.0	mA
Strobe input current	I _{st}	V _{IN} =35V, V _{st} =5V, I _O =0A, *			1.0	mA

[L780S08]

Recommended Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings		Unit
Input voltage range	V _{IN}		10.5 to 23.0		V
Output current range	I _O		5 to 1000		mA

Operating Characteristics at T_j=25°C, V_{IN}=15V, I_O=500mA, V_{st}=0V, *Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output voltage	V _{O1}		7.7	8.0	8.3	V
	V _{O2}	10.5V≤V _{IN} ≤23V, 5mA≤V _{IN} ≤1A	7.6		8.4	V
Line regulation 1	ΔV _{OLN1}	10.5V≤V _{IN} ≤25V		6.0	160	mV
Line regulation 2	ΔV _{OLN2}	11V≤V _{IN} ≤17V		2.0	80	mV
Load regulation 1	ΔV _{OLD1}	5mA≤I _O ≤1.5A			160	mV
Load regulation 2	ΔV _{OLD2}	250mA≤I _O ≤750mA			80	mV
Current dissipation	I _{CC}				8.0	mA
Current dissipation variation (Line)	ΔI _{CCLN}	10.5V≤V _{IN} ≤25V			1.0	mA
Current dissipation variation (Load)	ΔI _{CCLD}	5mA≤I _O ≤1A			0.5	mA
Output noise voltage	V _{NO}	10Hz≤f≤100kHz*		52		µV
Ripple rejection	R _r	f=120Hz, 11.5V≤V _{IN} ≤21.5V	56	72		dB
Dropout voltage	V _{drop}	I _O =1A		2.0		V
Output short current	I _{OS}	V _{IN} =35V		0.75		A
Peak output current	I _{OP}			2.2		A
Output voltage at strobe mode	V _O (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			0.8	V
Current dissipation at strobe mode	I _{CC} (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			3.0	mA
Strobe input current	I _{st}	V _{IN} =35V, V _{st} =5V, I _O =0A, *			1.0	mA

[L780S09]

Recommended Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
Input voltage range	V _{IN}		11.5 to 25.0			V
Output current range	I _O		5 to 1000			mA

Operating Characteristics at T_j=25°C, V_{IN}=16V, I_O=500mA, V_{st}=0V, *Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output voltage	V _{O1}		8.64	9.0	9.36	V
	V _{O2}	11.5V≤V _{IN} ≤24V, 5mA≤V _{IN} ≤1A	8.55		9.45	V
Line regulation 1	ΔV _{OLN1}	11.5V≤V _{IN} ≤25V		7	180	mV
Line regulation 2	ΔV _{OLN2}	12V≤V _{IN} ≤20V		2	90	mV
Load regulation 1	ΔV _{OLD1}	5mA≤I _O ≤1.5A			180	mV
Load regulation 2	ΔV _{OLD2}	250mA≤I _O ≤750mA			90	mV
Current dissipation	I _{CC}				8.0	mA
Current dissipation variation (Line)	ΔI _{CCLN}	11.5V≤V _{IN} ≤26V			1.0	mA
Current dissipation variation (Load)	ΔI _{CCLD}	5mA≤I _O ≤1A			0.5	mA
Output noise voltage	V _{NO}	10Hz≤f≤100kHz*		57		µV
Ripple rejection	R _r	f=120Hz, 12V≤V _{IN} ≤22V	56	72		dB
Dropout voltage	V _{drop}	I _O =1A			2.0	V
Output short current	I _{OS}	V _{IN} =35V			0.75	A
Peak output current	I _{OP}				2.2	A
Output voltage at strobe mode	V _O (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			0.8	V
Current dissipation at strobe mode	I _{CC} (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			3.0	mA
Strobe input current	I _{st}	V _{IN} =35V, V _{st} =5V, I _O =0A, *			1.0	mA

[L780S10]

Recommended Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
Input voltage range	V _{IN}		13.0 to 25.0			V
Output current range	I _O		5 to 1000			mA

Operating Characteristics at T_j=25°C, V_{IN}=17V, I_O=500mA, V_{st}=0V, *Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output voltage	V _{O1}		9.6	10.0	10.4	V
	V _{O2}	12.5V≤V _{IN} ≤25V, 5mA≤V _{IN} ≤1A	9.5		10.5	V
Line regulation 1	ΔV _{OLN1}	12.5V≤V _{IN} ≤28V		8	200	mV
Line regulation 2	ΔV _{OLN2}	14V≤V _{IN} ≤20V		2.5	100	mV
Load regulation 1	ΔV _{OLD1}	5mA≤I _O ≤1.5A			200	mV
Load regulation 2	ΔV _{OLD2}	250mA≤I _O ≤750mA			100	mV
Current dissipation	I _{CC}				8.0	mA
Current dissipation variation (Line)	ΔI _{CCLN}	12.5V≤V _{IN} ≤25V			1.0	mA
Current dissipation variation (Load)	ΔI _{CCLD}	5mA≤I _O ≤1A			0.5	mA
Output noise voltage	V _{NO}	10Hz≤f≤100kHz*		63		µV
Ripple rejection	R _r	f=120Hz, 13V≤V _{IN} ≤23V	55	72		dB
Dropout voltage	V _{drop}	I _O =1A			2.0	V
Output short current	I _{OS}	V _{IN} =35V			0.75	A
Peak output current	I _{OP}				2.2	A
Output voltage at strobe mode	V _O (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			0.8	V
Current dissipation at strobe mode	I _{CC} (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			3.0	mA
Strobe input current	I _{st}	V _{IN} =35V, V _{st} =5V, I _O =0A, *			1.0	mA

[L780S12]

Recommended Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings		Unit
Input voltage range	V _{IN}		15.0 to 27.0		V
Output current range	I _O		5 to 1000		mA

Operating Characteristics at T_j=25°C, V_{IN}=19V, I_O=500mA, V_{st}=0V, *Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output voltage	V _{O1}		11.5	12.0	12.5	V
	V _{O2}	14.5V≤V _{IN} ≤27V, 5mA≤V _{IN} ≤1A	11.4		12.6	V
Line regulation 1	ΔV _{OLN1}	14.5V≤V _{IN} ≤30V		10	240	mV
Line regulation 2	ΔV _{OLN2}	16V≤V _{IN} ≤22V		3	120	mV
Load regulation 1	ΔV _{OLD1}	5mA≤I _O ≤1.5A			240	mV
Load regulation 2	ΔV _{OLD2}	250mA≤I _O ≤750mA			120	mV
Current dissipation	I _{CC}				8.0	mA
Current dissipation variation (Line)	ΔI _{CCLN}	14.5V≤V _{IN} ≤30V			1.0	mA
Current dissipation variation (Load)	ΔI _{CCLD}	5mA≤I _O ≤1A			0.5	mA
Output noise voltage	V _{NO}	10Hz≤f≤100kHz*		75		µV
Ripple rejection	R _r	f=120Hz, 15V≤V _{IN} ≤25V	55	71		dB
Dropout voltage	V _{drop}	I _O =1A			2.0	V
Output short current	I _{OS}	V _{IN} =35V			0.75	A
Peak output current	I _{OP}				2.2	A
Output voltage at strobe mode	V _O (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			0.8	V
Current dissipation at strobe mode	I _{CC} (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			3.0	mA
Strobe input current	I _{st}	V _{IN} =35V, V _{st} =5V, I _O =0A, *			1.0	mA

[L780S15]

Recommended Operating Conditions at Ta=25°C

Parameter	Symbol	Conditions	Ratings		Unit
Input voltage range	V _{IN}		18.0 to 30.0		V
Output current range	I _O		5 to 1000		mA

Operating Characteristics at T_j=25°C, V_{IN}=23V, I_O=500mA, V_{st}=0V, *Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output voltage	V _{O1}		14.4	15.0	15.6	V
	V _{O2}	17.5V≤V _{IN} ≤30V, 5mA≤V _{IN} ≤1A	14.25		15.75	V
Line regulation 1	ΔV _{OLN1}	17.5V≤V _{IN} ≤30V		11	300	mV
Line regulation 2	ΔV _{OLN2}	20V≤V _{IN} ≤26V		3	150	mV
Load regulation 1	ΔV _{OLD1}	5mA≤I _O ≤1.5A			300	mV
Load regulation 2	ΔV _{OLD2}	250mA≤I _O ≤750mA			150	mV
Current dissipation	I _{CC}				8.0	mA
Current dissipation variation (Line)	ΔI _{CCLN}	17.5V≤V _{IN} ≤30V			1.0	mA
Current dissipation variation (Load)	ΔI _{CCLD}	5mA≤I _O ≤1A			0.5	mA
Output noise voltage	V _{NO}	10Hz≤f≤100kHz*		90		µV
Ripple rejection	R _r	f=120Hz, 18.5V≤V _{IN} ≤28.5V	54	70		dB
Dropout voltage	V _{drop}	I _O =1A			2.0	V
Output short current	I _{OS}	V _{IN} =35V			0.75	A
Peak output current	I _{OP}				2.2	A
Output voltage at strobe mode	V _O (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			0.8	V
Current dissipation at strobe mode	I _{CC} (ston)	V _{IN} =35V, V _{st} =5V, I _O =0A, *			3.0	mA
Strobe input current	I _{st}	V _{IN} =35V, V _{st} =5V, I _O =0A, *			1.0	mA

[L780S18]

Recommended Operating Conditions at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Input voltage range	V_{IN}		21.0 to 33.0	V
Output current range	I_O		5 to 1000	mA

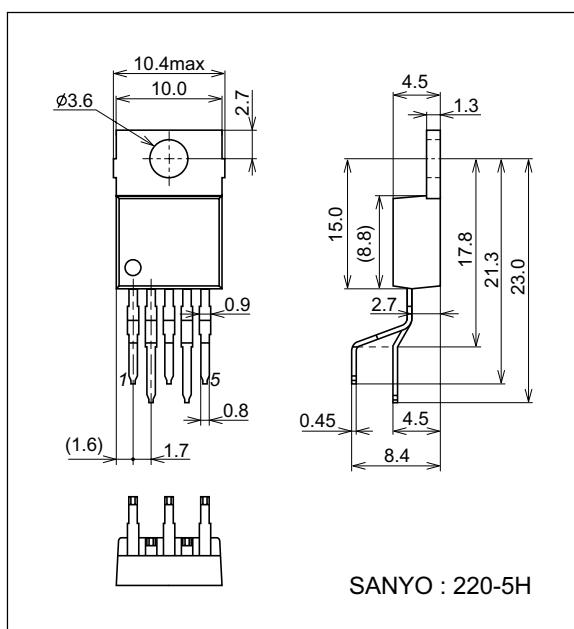
Operating Characteristics at $T_j=25^\circ\text{C}$, $V_{IN}=27\text{V}$, $I_O=500\text{mA}$, $V_{st}=0\text{V}$, * $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Output voltage	V_{O1}		17.3	18.0	18.7	V
	V_{O2}	$21\text{V} \leq V_{IN} \leq 33\text{V}$, $5\text{mA} \leq I_O \leq 1\text{A}$	17.1		18.9	V
Line regulation 1	ΔV_{OLN1}	$21\text{V} \leq V_{IN} \leq 33\text{V}$		15	360	mV
Line regulation 2	ΔV_{OLN2}	$24\text{V} \leq V_{IN} \leq 30\text{V}$		5	180	mV
Load regulation 1	ΔV_{OLD1}	$5\text{mA} \leq I_O \leq 1.5\text{A}$			360	mV
Load regulation 2	ΔV_{OLD2}	$250\text{mA} \leq I_O \leq 750\text{mA}$			180	mV
Current dissipation	I_{CC}				8.0	mA
Current dissipation variation (Line)	ΔI_{CCLN}	$21\text{V} \leq V_{IN} \leq 33\text{V}$			1.0	mA
Current dissipation variation (Load)	ΔI_{CCLD}	$5\text{mA} \leq I_O \leq 1\text{A}$			0.5	mA
Output noise voltage	V_{NO}	$10\text{Hz} \leq f \leq 100\text{kHz}^*$		110		μV
Ripple rejection	R_r	$f=120\text{Hz}$, $22\text{V} \leq V_{IN} \leq 32\text{V}$	53	69		dB
Dropout voltage	V_{drop}	$I_O=1\text{A}$			2.0	V
Output short current	I_{OS}	$V_{IN}=35\text{V}$			0.75	A
Peak output current	I_{OP}				2.2	A
Output voltage at strobe mode	$V_O(\text{ston})$	$V_{IN}=35\text{V}$, $V_{st}=5\text{V}$, $I_O=0\text{A}$, *			0.8	V
Current dissipation at strobe mode	$I_{CC}(\text{ston})$	$V_{IN}=35\text{V}$, $V_{st}=5\text{V}$, $I_O=0\text{A}$, *			3.0	mA
Strobe input current	I_{st}	$V_{IN}=35\text{V}$, $V_{st}=5\text{V}$, $I_O=0\text{A}$, *			1.0	mA

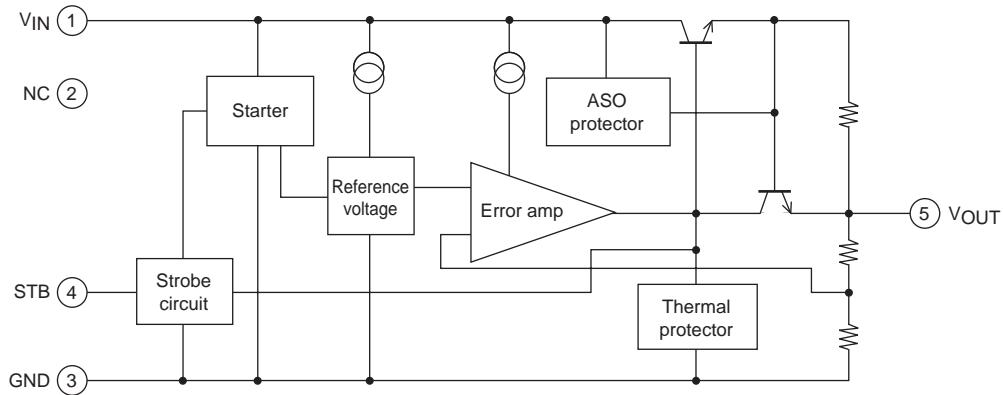
Package Dimensions

unit : mm

3079C

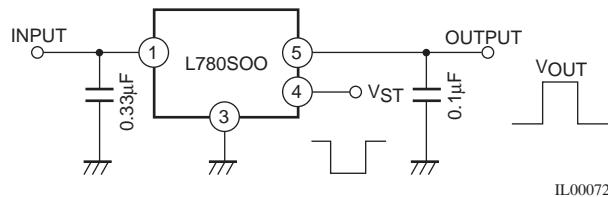


Equivalent Circuit Block Diagram

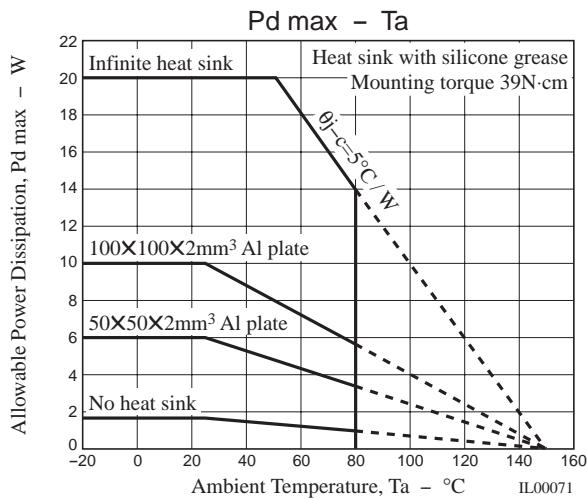


IL00073

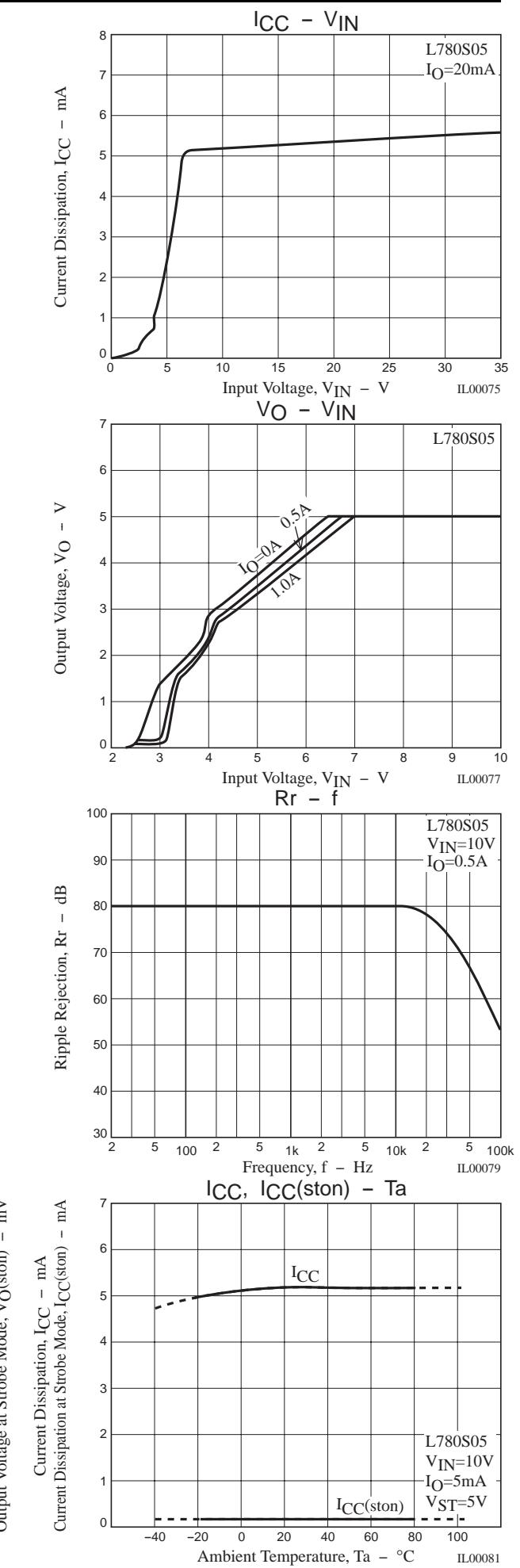
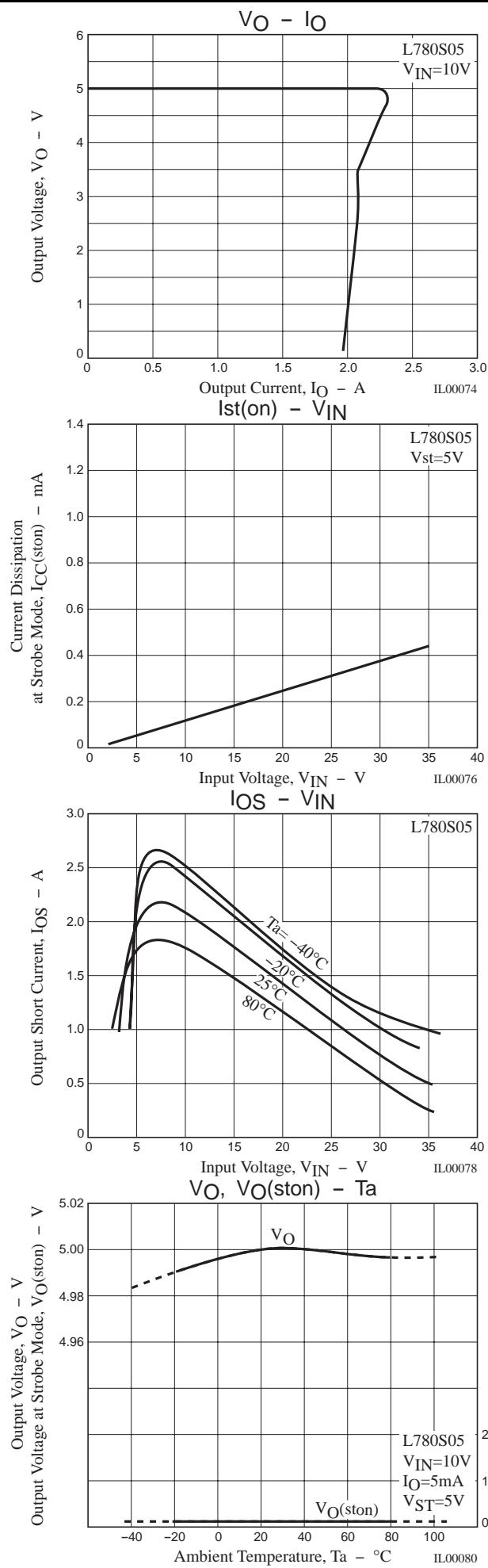
DC Characteristics Test Circuit (Common to L780S00 series)

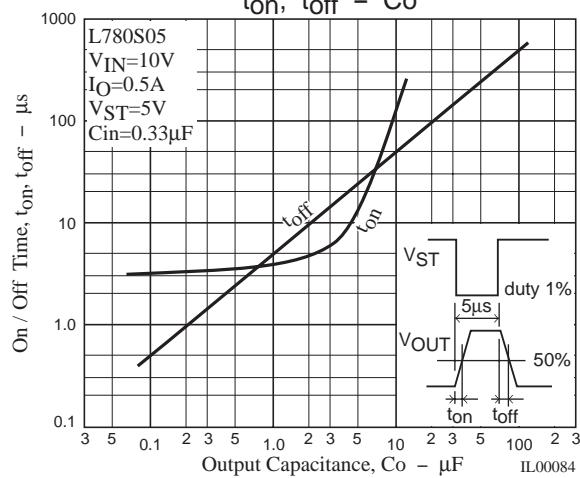
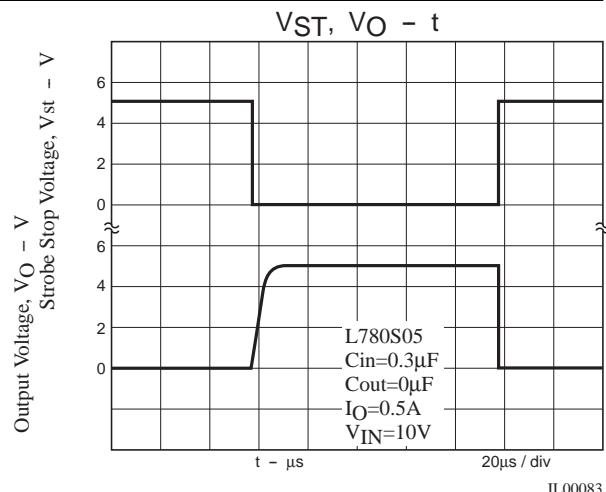
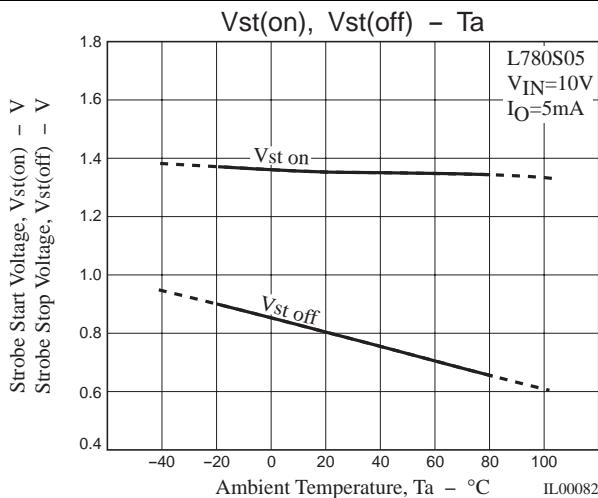


IL00072



IL00071





- Specifications of any and all SANYO Semiconductor products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- SANYO Semiconductor Co., Ltd. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all SANYO Semiconductor products (including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of SANYO Semiconductor Co., Ltd.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the SANYO Semiconductor product that you intend to use.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. SANYO Semiconductor believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.

This catalog provides information as of June, 2006. Specifications and information herein are subject to change without notice.